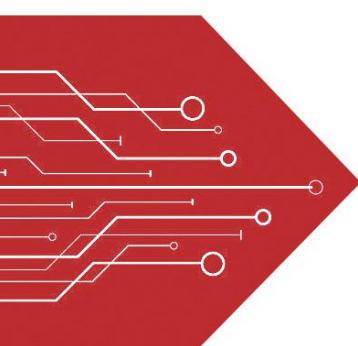


MSKSEMI

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ESD



TVS



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MOV



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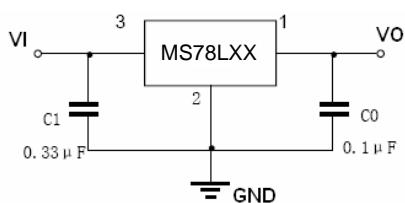


PLED

Product data sheet



SOT-89



FEATURES

- Wide range of available, fixed output voltage.
- Low cost.
- Internal short-circuit current limiting.
- Internal thermal overload protection.
- No external components required.
- Complementary negative regulators offered (79LXX series).

APPLICATIONS

- Three-terminal positive voltage regulator.

MAXIMUM RATING operating temperature range applies unless otherwise specified

Symbol	Parameter	Value	Units
V _I	Input voltage(3.3V-9V) (10V-15V) (18V-24V)	30 35 40	V
I _{CM}	Maximum output current	100	mA
P _D	Power dissipation	500	mW
T _{OPR}	Operating junction temperature	-40 to +125	°C
T _j , T _{stg}	Storage temperature range	-40 to +150	°C

ELECTRICAL CHARACTERISTICS

● MS78L33
 $(V_{IN}=10V, I_O=40mA, 0^\circ C < T_j < 125^\circ C, C_I=0.33\mu F, C_O=0.1\mu F, \text{unless otherwise specified})$

Parameter	Symbol	Test conditions	MS78L33			UNIT
			MIN	TYP	MAX	
Output voltage	V_O	$T_j=25^\circ C$ $5.3V \leq V_i \leq 20V, I_O=1mA-40mA$ $V_1=8.3V, I_O=1mA-70mA$	3.168 3.135 3.135	3.3	3.432 3.465 3.465	V
Load regulation	Reg_{load}	$T_j=25^\circ C, I_O=1mA-100mA$ $T_j=25^\circ C, I_O=1mA-40mA$			60 30	mV
Line regulation	Reg_{line}	$5.3V \leq V_i \leq 20V, T_j=25^\circ C$ $6.3V \leq V_i \leq 20V, T_j=25^\circ C$			150 100	mV
Input Bias Current	I_{IB}	$T_j=25^\circ C$ $T_j=125^\circ C$			6.0 5.5	mA
Input Bias Current Change	ΔI_{IB}	$6.3V \leq V_i \leq 20V$ $1mA \leq I_O \leq 40mA$			1.5 0.1	mA
Output noise voltage	V_N	$10Hz \leq f \leq 100KHz$		40		μV
Ripple rejection	RR	$I_O=40mA, 6.3V \leq V_i \leq 16.3V$ $f=120Hz, T_j=25^\circ C$	41	49		dB
Dropout voltage	V_I-V_O	$T_j=25^\circ C$		1.7		V

ELECTRICAL CHARACTERISTICS

● MS78L05
 $(V_{IN}=10V, I_O=40mA, 0^\circ C < T_j < 125^\circ C, C_I=0.33\mu F, C_O=0.1\mu F, \text{unless otherwise specified})$

Parameter	Symbol	Test conditions	78L05			UNIT
			MIN	TYP	MAX	
Output voltage	V_O	$T_j=25^\circ C$ $7V \leq V_i \leq 20V, I_O=1mA-40mA$ $V_1=10V, I_O=1mA-70mA$	4.8 4.75 4.75	5.0	5.2 5.25 5.25	V
Load regulation	Reg_{load}	$T_j=25^\circ C, I_O=1mA-100mA$ $T_j=25^\circ C, I_O=1mA-40mA$		11 5	60 30	mV
Line regulation	Reg_{line}	$7V \leq V_i \leq 20V, T_j=25^\circ C$ $8V \leq V_i \leq 20V, T_j=25^\circ C$		55 45	150 100	mV
Input Bias Current	I_{IB}	$T_j=25^\circ C$ $T_j=125^\circ C$		3.8	6.0 5.5	mA
Input Bias Current Change	ΔI_{IB}	$8V \leq V_i \leq 20V$ $1mA \leq I_O \leq 40mA$			1.5 0.1	mA
Output noise voltage	V_N	$10Hz \leq f \leq 100KHz$		40		μV
Ripple rejection	RR	$I_O=40mA, 8V \leq V_i \leq 18V, f=120Hz$ $, T_j=25^\circ C$	41	49		dB
Dropout voltage	V_I-V_O	$T_j=25^\circ C$		1.7		V

ELECTRICAL CHARACTERISTICS

- **MS78L06** ($V_{IN}=12V, I_O=40mA, 0^\circ C < T_j < 125^\circ C, C_i=0.33\mu F, C_o=0.1\mu F$, unless otherwise specified)

Parameter	Symbol	Test conditions	MS78L06			UNIT
			MIN	TYP	MAX	
Output voltage	V_O	$T_j=25^\circ C$ $V_1=8.5V-20V, I_O=1mA-40mA$ $V_1=8.5V, I_O=1mA-70mA$	5.75 5.7 5.7	6.0	6.25 6.3 6.3	V
Load regulation	Reg_{load}	$T_j=25^\circ C, I_O=1mA-100mA$ $T_j=25^\circ C, I_O=1mA-70mA$		12.8 5.8	80 40	mV
Line regulation	Reg_{line}	$8.5V \leq V_i \leq 20V, T_j=25^\circ C$ $9V \leq V_i \leq 20V, T_j=25^\circ C$		64 54	175 125	mV
Input Bias Current	I_{IB}	$T_j=25^\circ C, V_{IN}=12V, I_O=40mA$ $T_j=125^\circ C, V_{IN}=12V, I_O=40mA$		3.9	5.5 6.0	mA
Input Bias Current Change	ΔI_{IB}	$9V \leq V_i \leq 20V$ $1mA \leq I_O \leq 40mA$			1.5 0.1	mA
Output noise voltage	V_N	$10Hz \leq f \leq 100KHz$		40		$\mu V/V_O$
Ripple rejection	RR	$I_O=40mA, 10V \leq V_i \leq 20V, f=120Hz, T_j=25^\circ C$	40	46		dB
Dropout voltage	V_D	$T_j=25^\circ C$		1.7		V

ELECTRICAL CHARACTERISTICS

- **MS78L08** ($V_i=14V, I_O=40mA, 0^\circ C < T_j < 125^\circ C, C_i=0.33\mu F, C_o=0.1Mf$, unless otherwise specified)

Parameter	Symbol	Test conditions	MS78L08			UNIT
			MIN	TYP	MAX	
Output voltage	V_O	$T_j=25^\circ C$ $10.5V \leq V_i \leq 23V, I_O=1mA-40mA$ $V_i=14V, I_O=1mA-70mA$	7.7 7.6 7.6	8.0	8.3 8.4 8.4	V
Load regulation	Reg_{load}	$T_j=25^\circ C, I_O=1mA-100mA$ $T_j=25^\circ C, I_O=1mA-40mA$		15 8.0	80 40	mV
Line regulation	Reg_{line}	$10.5V \leq V_i \leq 23V, T_j=25^\circ C$ $11V \leq V_i \leq 23V, T_j=25^\circ C$		20 12	175 125	mV
Input Bias Current	I_{IB}	$T_j=25^\circ C$ $T_j=125^\circ C$		3	6.0 5.5	mA
Input Bias Current Change	ΔI_{IB}	$11V \leq V_i \leq 23V$ $1mA \leq I_O \leq 40mA$			1.5 0.1	mA
Output noise voltage	V_N	$T_A=25^\circ C, 10Hz \leq f \leq 100KHz$		60		μV
Ripple rejection	RR	$I_O=40mA, 12V \leq V_i \leq 23V, f=120Hz, T_j=25^\circ C$	37	57		dB
Dropout voltage	V_i-V_O	$T_j=25^\circ C$		1.7		V

ELECTRICAL CHARACTERISTICS

- **MS78L09** ($V_i=15V, I_o=40mA, 0^\circ C < T_j < 125^\circ C, C_l=0.33\mu F, C_o=0.1\mu F$, unless otherwise specified)

Parameter	Symbol	Test conditions	MS78L09			UNIT
			MIN	TYP	MAX	
Output voltage	V_o	$T_j=25^\circ C$ $V_i=11.5V-24V, I_o=1mA-40mA$ $V_i=15V, I_o=1mA-70mA$	8.6 8.5 8.5	9.0	9.4 9.5 9.5	V
Load regulation	Reg_{load}	$T_j=25^\circ C, I_o=1mA-100mA$ $T_j=25^\circ C, I_o=1mA-40mA$		15 8.0	90 40	mV
Line regulation	Reg_{line}	$11.5V \leq V_i \leq 24V, T_j=25^\circ C$ $12V \leq V_i \leq 24V, T_j=25^\circ C$		20 12	175 125	mV
Input Bias Current	I_{IB}	$T_j=25^\circ C$ $T_j=125^\circ C$		3.0	6.0 5.5	mA
Input Bias Current Change	ΔI_{IB}	$11V \leq V_i \leq 23V$ $1mA \leq I_o \leq 40mA$			1.5 0.1	mA
Output noise voltage	V_N	$T_A=25^\circ C, 10Hz \leq f \leq 100KHz$		60		μV
Ripple rejection	RR	$I_o=40mA, 13V \leq V_i \leq 24V, f=120Hz$ $T_j=25^\circ C$	37	57		dB
Dropout voltage	V_i-V_o	$T_j=25^\circ C$		1.7		V

ELECTRICAL CHARACTERISTICS

- **MS78L10** ($V_{IN}=16V, I_o=40mA, C_{IN}=0.33\mu F, C_o=0.1\mu F$, $T_j = 0$ to $125^\circ C$, unless otherwise specified)

Parameter	Symbol	Test conditions	MS78L10			UNIT
			MIN	TYP	MAX	
Output voltage	V_o	$T_j=25^\circ C$	9.6	10	10.4	V
Load regulation(Note1)	ΔReg_{load}	$I_o = 1$ to $100mA, T_j = 25^\circ C$	-	17	90	mV
		$I_o = 1$ to $40mA, T_j = 25^\circ C$	-	9	45	mV
Line regulation(Note1)	ΔReg_{line}	$V_i = 12.5$ to $25V, T_j = 25^\circ C$	-	100	210	mV
		$V_i = 13$ to $25V, T_j = 25^\circ C$	-	90	160	mV
Input Bias Current	I_{IB}	$T_j = 25^\circ C$	-	2.0	3.0	mA
Input Bias Current Change	ΔI_{IB}	$V_i = 13$ to $25V, T_j = 25^\circ C$	-	-	1.0	mA
Output Noise Voltage	V_N	$10Hz \leq f \leq 100KHz$	-	70	-	μV
Ripple Rejection	RR	$V_i = 13$ to $23V, I_o = 40mA, f = 120Hz$	42	52	-	dB
Dropout Voltage	V_D	$T_j=25^\circ C$	-	1.7	-	V
Dropout voltage	V_i-V_o	$I_o = 5mA, T_j = 0$ to $125^\circ C$	-	0.9	-	$mV/^\circ C$

ELECTRICAL CHARACTERISTICS

- **MS78L12**

($V_i=19V, I_o=40mA, 0^\circ C < T_j < 125^\circ C, C_l=0.33\mu F, C_o=0.1\mu F$, unless otherwise specified)

Parameter	Symbol	Test conditions	MS78L12			UNIT
			MIN	TYP	MAX	
Output voltage	V_o	$T_j=25^\circ C$	11.5	12	12.5	V
		$V_i=14.5V-27V, I_o=1mA-40mA$	11.4		12.6	
		$V_i=19V, I_o=1mA-70mA$	11.4		12.6	
Load regulation	Reg_{load}	$T_j=25^\circ C, I_o=1mA-100mA$		20	100	mV
		$T_j=25^\circ C, I_o=1mA-40mA$		10	50	
Line regulation	Reg_{line}	$14.5V \leq V_i \leq 27V, T_j=25^\circ C$		120	250	mV
		$16V \leq V_i \leq 27V, T_j=25^\circ C$		100	200	
Input Bias Current	I_{IB}	$T_j=25^\circ C$		4.2	6.5	mA
		$T_j=125^\circ C$			6.0	
Input Bias Current Change	ΔI_{IB}	$16V \leq V_i \leq 27V$			1.5	mA
		$1mA \leq I_o \leq 40mA$			0.1	
Output Noise Voltage	V_N	$10Hz \leq f \leq 100KHz, T_A=25^\circ C$		80		μV
Ripple rejection	RR	$I_o=40mA, 15V \leq V_i \leq 25V, f=120Hz, T_j=25^\circ C$	37	42		dB
Dropout voltage	V_i-V_o	$T_j=25^\circ C$		1.7		V

ELECTRICAL CHARACTERISTICS

- **MS78L15**

($V_{IS}=23V, I_o=40mA, 0^\circ C < T_j < 125^\circ C, C_l=0.33\mu F, C_o=0.1\mu F$, unless otherwise specified)

Parameter	Symbol	Test conditions	MS78L15			UNIT
			MIN	TYP	MAX	
Output voltage	V_o	$T_j=25^\circ C$	14.4	15	15.6	V
		$V_i=17.5V-30V, I_o=1mA-40mA$	14.25		15.75	
		$V_i=23V, I_o=1mA-70mA$	14.25		15.75	
Load regulation	$\Delta \text{Reg}_{\text{load}}$	$T_j=25^\circ C, I_o=1mA-100mA$		25	150	mV
		$T_j=25^\circ C, I_o=1mA-40mA$		12	75	
Line regulation	$\Delta \text{Reg}_{\text{line}}$	$17.5V \leq V_i \leq 30V, T_j=25^\circ C$		130	300	mV
		$20V \leq V_i \leq 30V, T_j=25^\circ C$		110	250	
Input Bias Current	I_{IB}	$T_j=25^\circ C$		4.4	6.5	mA
		$T_j=125^\circ C$			6.0	
Input Bias Current Change	ΔI_{IB}	$20V \leq V_i \leq 30V$			1.5	mA
		$1mA \leq I_o \leq 40mA$			0.1	
Output noise voltage	V_N	$10Hz \leq f \leq 100KHz, T_A=25^\circ C$		90		μV
Ripple rejection	RR	$I_o=40mA, 18.5V \leq V_i \leq 28.5V, f=120Hz, T_j=25^\circ C$	34	39		dB
Dropout voltage	V_i-V_o	$T_j=25^\circ C$		1.7		V

ELECTRICAL CHARACTERISTICS

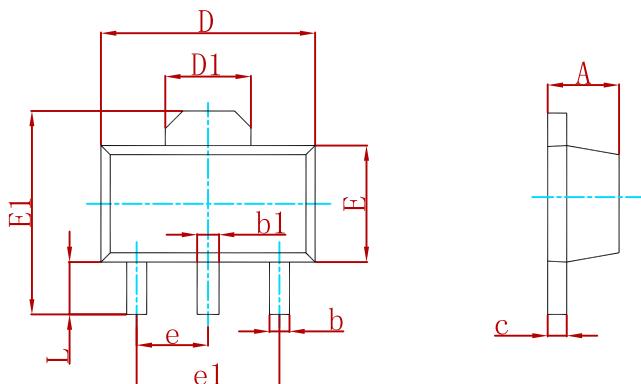
● **MS78L18**
(V_i=27V,I_O=40mA,0°C<T_j<125°C,C_I=0.33μF,C_O=0.1μf,unless otherwise specified)

Parameter	Symbol	Test conditions	MS78L18			UNIT
			MIN	TYP	MAX	
Output voltage	V _O	T _j =25°C V _i =20.7V-33V, I _O =1mA-40mA V _i =27V, I _O =1mA-70mA	17.3 17.1 17.1	18	18.7 18.9 18.9	V
Load regulation	Reg _{load}	T _j =25°C, I _O =1mA-100mA T _j =25°C, I _O =1mA-40mA		30 15	170 85	mV
Line regulation	Reg _{line}	20.7V≤V _i ≤33V, T _j =25°C 21V≤V _i ≤33V, T _j =25°C		45 35	325 275	mV
Input Bias Current	I _{IB}	T _j =25°C T _j =125°C		3.1	6.5 6.0	mA
Input Bias Current Change	△I _{IB}	21V≤V _i ≤33V 1mA≤I _O ≤40mA			1.5 0.1	mA
Output Noise Voltage	V _N	10Hz≤f≤100KHz, T _A =25°C		150		μV
Ripple rejection	RR	I _O =40mA, 23V≤V _i ≤33V, f=120Hz, T _j =25°C	33	48		dB
Dropout voltage	V _i -V _O	T _j =25°C		1.7		V

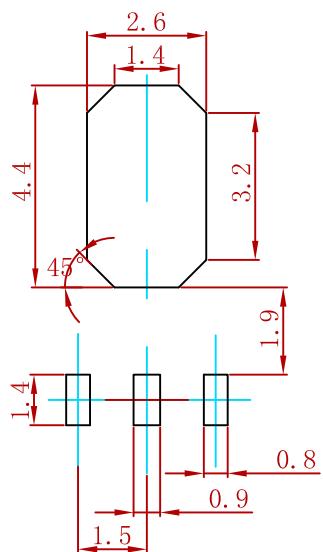
ELECTRICAL CHARACTERISTICS

● **MS78L24**
(V_{IS}=33V,I_O=40mA,0°C<T_j<125°C,C_I=0.33μF,C_O=0.1μf,unless otherwise specified)

Parameter	Symbol	Test conditions	78L24			UNIT
			MIN	TYP	MAX	
Output voltage	V _O	T _j =25°C V _i =27V-38V, I _O =1mA-40mA V _i =27V-33V, I _O =1mA-70mA	23 22.8 22.8	24	25 25.2 25.2	V
Load regulation	△Reg _{load}	T _j =25°C, I _O =1mA-100mA T _j =25°C, I _O =1mA-40mA		40 20	200 100	mV
Line regulation	△Reg _{line}	28V≤V _i ≤80V, T _j =25°C 27V≤V _i ≤38V, T _j =25°C		50 60	300 350	mV
Input Bias Current	I _{IB}	T _j =25°C T _j =125°C		3.1	6.5 6.0	mA
Input Bias Current Change	△I _{IB}	28V≤V _i ≤38V 1mA≤I _O ≤40mA			1.5 0.1	mA
Output noise voltage	V _N	10Hz≤f≤100KHz, T _A =25°C		200		μV
Ripple rejection	RR	I _O =40mA, 29V≤V _i ≤35V, f=120Hz, T _j =25°C	31	45		dB
Dropout voltage	V _i -V _O	T _j =25°C		1.7		V

PACKAGE MECHANICAL DATA


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.400	1.600	0.055	0.063
b	0.320	0.520	0.013	0.020
b1	0.400	0.580	0.016	0.023
c	0.350	0.440	0.014	0.017
D	4.400	4.600	0.173	0.181
D1	1.550	REF.	0.061	REF.
E	2.300	2.600	0.091	0.102
E1	3.940	4.250	0.155	0.167
e	1.500	TYP.	0.060	TYP.
e1	3.000	TYP.	0.118	TYP.
L	0.900	1.200	0.035	0.047

Suggested Pad Layout

Note:

1. Controlling dimension: in millimeters.
2. General tolerance: $\pm 0.05\text{mm}$.
3. The pad layout is for reference purposes only.

REEL SPECIFICATION

P/N	PKG	QTY
MS78XX	SOT-89	1000

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